

JAN2N6052 Information

Heisener.com

Part Number JAN2N6052

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS PNP DARL 100V 12A TO-3

Package TO-3

For the pricing/inventory/lead time, please contact

us

For Reference Only Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N6052 Specifications

Manufacturer Part Number	JAN2N6052
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-3
Series	Military, MIL-PRF-19500/501
Transistor Type	PNP - Darlington
Current - Collector (Ic) (Max)	12A
Voltage - Collector Emitter Breakdown (Max)	100V
Vce Saturation (Max) @ Ib, Ic	3V @ 120mA, 12A
Current - Collector Cutoff (Max)	1mA
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 6A, 3V
Power - Max	150W
Frequency - Transition	-
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-3
Supplier Device Package	TO-3 (TO-204AA)
	Report errors?

JAN2N6052 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N6052 Payment Methods



















JAN2N6052 Shipping Methods













If you have any question about JAN2N6052, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com